1



## SAM™ Data Sheet SAM-1064-14-2ps-x, λ = 1064 nm

Laser wavelength	$\lambda = 1064 \text{ nm}$
High reflection band	λ = 1000 1080 nm
Absorbance	A <sub>0</sub> = 14 %
Modulation depth	ΔR = 9 %
Non-saturable loss	A <sub>ns</sub> = 5 %
Saturation fluence	$\Phi_{sat}$ = 60 µJ/cm <sup>2</sup>
Relaxation time constant	τ = 2 ps
Damage threshold	$\Phi = 2 \text{ mJ/cm}^2$
Chip area	4.0 mm x 4.0 mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer
Mounting option <b>x</b> denotes the type of mounting as follows: <b>x</b> = 0 unmounted	
<b>x</b> = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm $\emptyset$

<b>x</b> = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm $\varnothing$
<b>x</b> = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm $\varnothing$
<b>x</b> = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm $arnothing$
<b>x</b> = FC	mounted on a 1 m single mode fiber cable with FC connector

## Low intensity spectral reflectance

